## NSN 5961-01-370-2826

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-370-2826 **Inclosure Material:** Metal **Overall Length:** 0.300 inches **Terminal Length:** 0.980 inches **Overall Diameter:** 0.450 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 500.00 amperes collector current, dc preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Nuclear Hardness Critical Feature:** Hardened **Test Data Document:** 88818-a531a256 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**